



GDEM029T94

Dalian Good Display Co., Ltd.



# **Product Specifications**





Customer	Standard			
Description	2.9" E-PAPER DISPLAY			
Model Name	GDEM029T94			
Date	2021/01/18			
Revision	1.3			

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# **Revision History**

Version	Content	Date	Producer
1.0	New release	2019/11/23	
1.1	Update storage condition for temperature and Humidity	2020/04/28	
1.2	Update Optical Specification	2020/09/07	
1.3	Updating	2021/01/18	



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#### 1. Over View

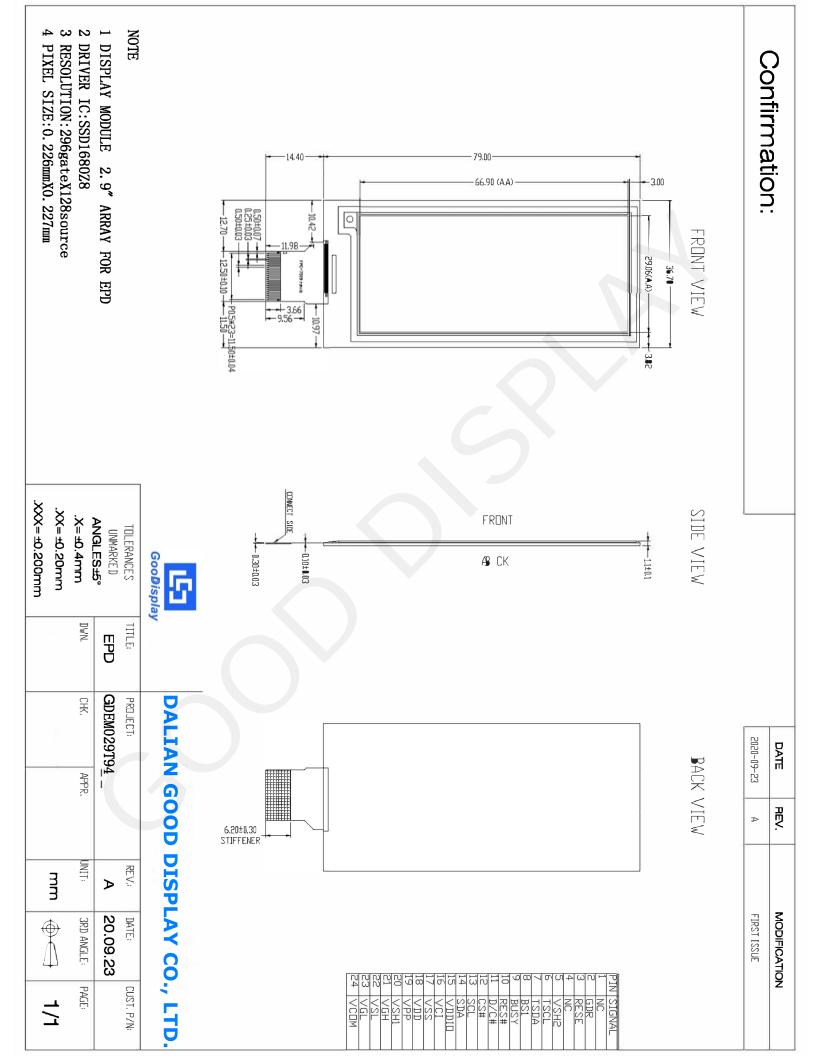
GDEM029T94 is an Active Matrix Electrophoretic Display (AM EPD), with interface and a reference system design. The display is capable to display images at 1-bit white, black full display capabilities. The 2.9 inch active area contains 296×128 pixels. The module is a TFT-array driving electrophoresis display, with integrated circuits including gate driver, source driver, MCU interface, timing controller, oscillator, DC-DC, SRAM, LUT, VCOM. Module can be used in portable electronic devices, such as Electronic Shelf Label (ESL) System.

#### 2. Features

- ♦296×128 pixels display
- ◆High contrast High reflectance
- ◆Ultra wide viewing angle Ultra low power consumption
- ◆Pure reflective mode
- ◆Bi-stable display
- ◆Commercial temperature range
- ◆Landscape portrait modes
- ◆Hard-coat antiglare display surface
- ◆Ultra Low current deep sleep mode
- ◆On chip display RAM
- ◆Waveform can stored in On-chip OTP or written by MCU
- ◆Serial peripheral interface available
- ◆On-chip oscillator
- ◆On-chip booster and regulator control for generating VCOM, Gate and Source driving voltage
- ◆I<sup>2</sup>C signal master interface to read external temperature sensor
- ◆Built-in temperature sensor

# 3. Mechanical Specification

Parameter	Specifications	Unit	Remark
Screen Size	2.9	Inch	
Display Resolution	128(H)×296(V)	Pixel	DPI:112
Active Area	66.90x29.06	mm	
Pixel Pitch	0.227×0.226	mm	
Pixel Configuration	Rectangle		
Outline Dimension	36.7(H)×79.0 (V) ×1.20(D)	mm	
Weight	5.5±0.5	g	





# 5. Input/output Pin Assignment

No.	Name	I/O	Description	Remark
1	NC		Do not connect with other NC pins	Keep Open
2	GDR	О	N-Channel MOSFET Gate Drive Control	
3	RESE	I	Current Sense Input for the Control Loop	
4	NC	NC	Do not connect with other NC pins	Keep Open
5	VSH2	С	Positive Source driving voltage(Red)	
6	TSCL	О	I2C Interface to digital temperature sensor Clock pin	
7	TSDA	I/O	I2C Interface to digital temperature sensor Data pin	
8	BS1	I	Bus Interface selection pin	Note 5-5
9	BUSY	О	Busy state output pin	Note 5-4
10	RES#	I	Reset signal input. Active Low.	Note 5-3
11	D/C#	I	Data /Command control pin	Note 5-2
12	CS#	I	Chip select input pin	Note 5-1
13	SCL	I	Serial Clock pin (SPI)	
14	SDA	I/O	Serial Data pin (SPI)	
15	VDDIO	Р	Power Supply for interface logic pins It should be connected with VCI	
16	VCI	P	Power Supply for the chip	
17	VSS	P	Ground	
18	VDD	С	Core logic power pin VDD can be regulated internally from VCI. A capacitor should be connected between VDD and VSS	
19	VPP	P	FOR TEST	Keep Open
20	VSH1	С	Positive Source driving voltage	
21	VGH	С	Power Supply pin for Positive Gate driving voltage and VSH1	
22	VSL	С	Negative Source driving voltage	
23	VGL	С	Power Supply pin for Negative Gate driving voltage VCOM and VSL	
24	VCOM	С	VCOM driving voltage	



I = Input Pin, O =Output Pin, I/O = Bi-directional Pin (Input/output), P = Power Pin, C = Capacitor Pin

**Note 5-1**: This pin (CS#) is the chip select input connecting to the MCU. The chip is enabled for MCU communication only when CS# is pulled LOW.

**Note 5-2**: This pin is (D/C#) Data/Command control pin connecting to the MCU in 4-wire SPI mode. When the pin is pulled HIGH, the data at SDA will be interpreted as data. When the pin is pulled LOW, the data at SDA will be interpreted as command.

Note 5-3: This pin (RES#) is reset signal input. The Reset is active low.

**Note 5-4**: This pin is Busy state output pin. When Busy is High, the operation of chip should not be interrupted, command should not be sent. The chip would put Busy pin High when -Outputting display waveform -Communicating with digital temperature sensor

**Note 5-5**: Bus interface selection pin

BS1 State	MCU Interface
L	4-lines serial peripheral interface(SPI) - 8 bits SPI
Н	3- lines serial peripheral interface(SPI) - 9 bits SPI

#### 6. Electrical Characteristics

## 6.1 Absolute Maximum Rating

Parameter	Symbol	Rating	Unit
Logic supply voltage	VCI	-0.5 to +6.0	V
Logic Input voltage	VIN	-0.5 to VCI +0.5	V
Logic Output voltage	VOUT	-0.5 to VCI +0.5	V
Operating Temp range	TOPR	0 to +50	°C.
Storage Temp range	TSTG	-25 to+70	°C.
Optimal Storage Temp	TSTGo	23±3	°C.
Optimal Storage Humidity	HSTGo	55±10	RH

#### Note:

Maximum ratings are those values beyond which damages to the device may occur. Functional operation should be restricted to the limits in the Panel DC Characteristics tables.



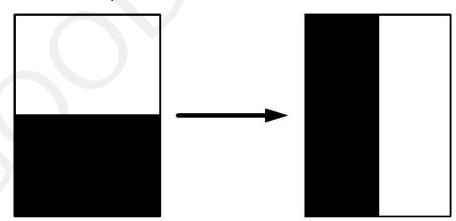
#### **6.2 Panel DC Characteristics**

The following specifications apply for: VSS=0V, VCI=3.0V, TOPR =25°C.

Parameter	Symbol	Condition	Applicab le pin	Min.	Typ.	Max.	Unit
Single ground	Vss	-		-	0	-	V
Logic supply voltage	Vci	-	VCI	2.2	3.0	3.7	V
Core logic voltage	$V_{\mathrm{DD}}$		VDD	1.7	1.8	1.9	V
High level input voltage	Vih	-	-	0.8 Vci	1		V
Low level input voltage	VIL	-	-	-	-	0.2 Vci	V
High level output voltage	Voh	IOH = -100uA	-	0.9 Vci	-	-	V
Low level output voltage	$V_{OL}$	IOL = 100uA	-	-	-	0.1 Vci	V
Typical power	Ртүр	V <sub>CI</sub> =3.0V	-	-	9.0	-	mW
Deep sleep mode	PSTPY	V <sub>CI</sub> =3.0V	-	-	0.003	-	mW
Typical operating current	Iopr_VCI	V <sub>CI</sub> =3.0V	-	-	3.0	-	mA
Image update time	-	25 °C	_	-	3	-	sec
Sleep mode current	Islp_Vci	DC/DC off No clock No input load Ram data retain		-	20		uA
Deep sleep mode current	Idslp_Vci	DC/DC off No clock No input load Ram data not retain	-	-	1	5	uA

#### **Notes:**

1. The typical power is measured with following transition from horizontal 2 scale pattern to vertical 2 scale pattern.



- 2. The deep sleep power is the consumed power when the panel controller is in deep sleep mode.
- 3. The listed electrical/optical characteristics are only guaranteed under the controller & waveform provided by Good Display.



## 6.3 Panel DC Characteristics(Driver IC Internal Regulators)

The following specifications apply for: VSS=0V, VCI=3.0V, TOPR =25°C.

Parameter	Symbol	Condition	Applicable pin	Min.	Typ.	Max.	Unit
VCOM output voltage	VCOM	-	VCOM	1	TBD	-	V
Positive Source output voltage	V <sub>SH</sub>	-	S <sub>0</sub> ~S <sub>127</sub>	+14.5	+15	+15.5	V
Negative Source output voltage	Vsl	-	S0~S127	-15.5	-15	-14.5	V
Positive gate output voltage	Vgh	-	G0~G295	+21	+22	+23	V
Negative gate output voltage	Vgl	-	G0~G295	-21	-20	-19	V

#### **6.4 Panel AC Characteristics**

#### 6.4.1 MCU Interface Selection

The pin assignment at different interface mode is summarized in Table 6-4-1. Different MCU mode can be set by hardware selection on BS1 pins. The display panel only supports 4-wire SPI or 3-wire SPI interface mode.

Pin Name	Data/Comm	and Interface	Control Signal			
Bus interface	SDA	SCL	CS#	D/C#	RES#	
BS1=L 4-wire SPI	SDA	SCL	CS#	D/C#	RES#	
BS1=H 3-wire SPI	SDA	SCL	CS#	L	RES#	

# 6.4.2 MCU Serial Interface (4-wire SPI)

The serial interface consists of serial clock SCL, serial data SDA, D/C#, CS#. This interface supports Write mode and Read mode.

Function	CS#	<b>D</b> /C#	SCL
Write command	L	L	<b>↑</b>
Write data	L	Н	<b>↑</b>

**Note:** ↑ stands for rising edge of signal

In the write mode SDA is shifted into an 8-bit shift register on every rising edge of SCL in the order of D7, D6, ... D0. The level of D/C# should be kept over the whole byte . The data byte in the shift register is written to the Graphic Display Data RAM /Data Byte register or command Byte register according to D/C# pin.

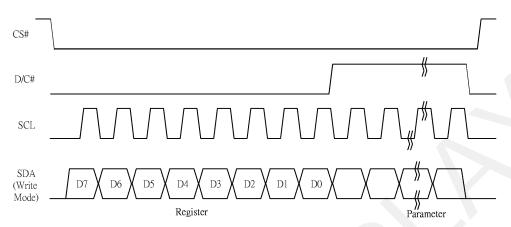


Figure 6-1: Write procedure in 4-wire SPI mode

#### In the Read mode:

- 1. After driving CS# to low, MCU need to define the register to be read.
- 2. SDA is shifted into an 8-bit shift register on every rising edge of SCL in the order of D7, D6, ... D0 with D/C# keep low.
- 3. After SCL change to low for the last bit of register, D/C# need to drive to high.
- 4. SDA is shifted out an 8-bit data on every falling edge of SCL in the order of D7, D6, ... D0.
- 5. Depending on register type, more than 1 byte can be read out. After all byte are read, CS# need to drive to high to stop the read operation.

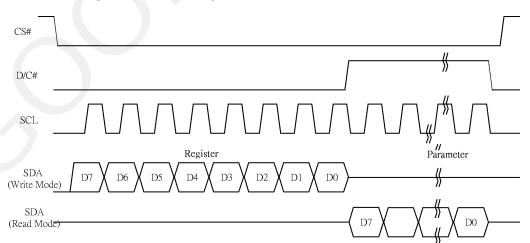


Figure 6-2: Read procedure in 4-wire SPI mode



## 6.4.3 MCU Serial Interface (3-wire SPI)

The 3-wire serial interface consists of serial clock SCL, serial data SDA and CS#. This interface also supports Write mode and Read mode.

The operation is similar to 4-wire serial interface while D/C# pin is not used. There are altogether 9-bits will be shifted into the shift register on every ninth clock in sequence: D/C# bit, D7 to D0 bit. The D/C# bit (first bit of the sequential data) will determine the following data byte in the shift register is written to the Display Data RAM (D/C# bit = 1) or the command register (D/C# bit = 0).

Function	CS#	D/C#	SCL
Write command	L	Tie	1
Write data	L	Tie	1

Note: ↑ stands for rising edge of signal

SDA (Write Mode)

Register

Register

CS#

SDA (D5 D4 D3 D2 D1 D0 1 D7 Parameter

Figure 6-3: Write procedure in 3-wire SPI mode

#### In the Read mode:

- 1. After driving CS# to low, MCU need to define the register to be read.
- 2. D/C=0 is shifted thru SDA with one rising edge of SCL
- 3. SDA is shifted into an 8-bit shift register on every rising edge of SCL in the order of D7, D6, ... D0.
- 4. D/C=1 is shifted thru SDA with one rising edge of SCL
- 5. SDA is shifted out an 8-bit data on every falling edge of SCL in the order of D7, D6,  $\dots$  D0.
- 6. Depending on register type, more than 1 byte can be read out. After all byte are read, CS# need to drive to high to stop the read operation.

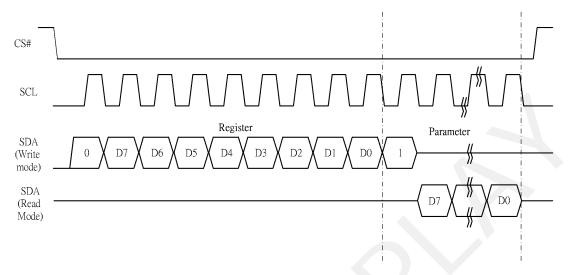
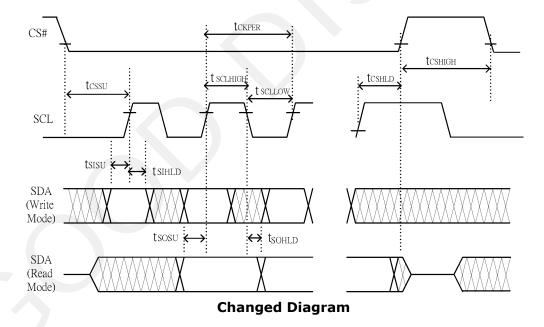


Figure 6-4: Read procedure in 3-wire SPI mode

# 6.4.4 Interface Timing

The following specifications apply for: VSS=0V, VCI=3.0V,  $TOPR=25^{\circ}C$ .





# **Serial Interface Timing Characteristics**

(VCI - VSS = 2.2V to 3.7V, TOPR = 25°C, CL=20pF)

### Write mode

Symbol	Parameter	Min	Тур.	Max	Unit
fSCL	SCL frequency (Write Mode)		4	20	MHz
tCSSU	Time CS# has to be low before the first rising edge of SCLK	60			ns
tCSHLD	Time CS# has to remain low after the last falling edge of SCLK	65			ns
tCSHIGH	Time CS# has to remain high between two transfers	100			ns
tSCLHIGH	Part of the clock period where SCL has to remain high	25			ns
tSCLLOW	Part of the clock period where SCL has to remain low	25			ns
tSISU	Time SI (SDA Write Mode) has to be stable before the next rising edge of SCL	10			ns
tSIHLD	Time SI (SDA Write Mode) has to remain stable after the rising edge of SCL	40			ns

#### **Read mode**

Symbol	Parameter	Min	Тур.	Max	Unit
fSCL	SCL frequency (Read Mode)			2.5	MHz
tCSSU	Time CS# has to be low before the first rising edge of SCLK	100			ns
tCSHLD	Time CS# has to remain low after the last falling edge of SCLK	50			ns
tCSHIGH	Time CS# has to remain high between two transfers	250			ns
tSCLHIG H	Part of the clock period where SCL has to remain high	180			ns
tSCLLOW	Part of the clock period where SCL has to remain low	180			ns
tSOSU	Time SO(SDA Read Mode) will be stable before the next rising edge of SCL		50		ns
tSOHLD	Time SO (SDA Read Mode) will remain stable after the falling edge of SCL		0		ns



# 7.Command Table

R/W#	D/C#	Hex	D7	D6	D5	D4	D3	D2	D1	D0	Comman d	Description
0	0	01	0	0	0	0	0	0	0	1	Driver	Gate setting
0	1		A7	A6	A5	A4	A3	A2	A1	A0	Output	Set A[8:0]=0097h
0	1		0	0	0	0	0	0	0	A8	control	Set B[8:0]=00h
0	1		0	0	0	0	0	B2	B1	В0		
0	0	03	0	0	0	0	0	0	1	1	Gate	SetGate Driving voltage
0	1		0	0	0	A4	A3	A2	A1	A0	Driving voltage control	A[4:0]=17h[POR],VGH at 20V[POR] VGH setting from 10V to 20V
0	0	04	0	0	0	0	0	1	0	0	Source	SetSource Driving voltage
0	1		A7	A6	A5	A4	A3	A2	A1	A0	Driving	A[7:0]= 41h[POR],VSH1 at 15V
0	1		В7	В6	B5	B4	В3	B2	B1	В0	voltage control	B[7:0]=A Ch[POR], VSH2 at 5.4V C[7:0]= 32h[POR], VSL at -15V
0	1		C7	C6	C5	C4	C3	C2	C1	C0	Control	521[1 OK], VBE ut 13 V
0	0	08	0	0	0	0	1	0	0	0	Initial Code Setting OTP Program	Program Initial Code Setting The command required CLKEN=1. Refer to Register 0x22 for detail. BUSY pad will output high during operation
0	0	09	0	0	0	0	1	0	0	1	Write	Write Register for Initial Code Setting
0	1		A7	A6	A5	A4	A3	A2	<b>A</b> 1	A0	Register	Selection
0	1		В7	В6	В5	B4	В3	B2	B1	В0	for Initial Code	A[7:0] ~ D[7:0]: Reserved Details refer to Application Notes of Initial
0	1		C7	C6	C5	C4	C3	C2	C1	C0	Setting	Code Setting
0	1		D7	D6	D5	D4	D3	D2	D1	D0		- Company of the Comp
0	0	0A	0	0	0	0	1	0	1	0	Read Register for Initial Code Setting	Read Register for Initial Code Setting
0	0	10	0	0	0	1	0	0	0	0	Deep	Deep Sleep mode Control:
0	1		0	0	0	0	0	0	0	$A_0$	Sleep	A[1:0]: Description
											mode	00 Normal Mode [POR] 01 Enter Deep Sleep Mode 1 11 Enter Deep Sleep Mode 2 After this command initiated, the chip will enter Deep Sleep Mode, BUSY pad will keep output high. Remark: To Exit Deep Sleep mode, User required to send HWRESET to the driver



0	0	11	0	0	0	1	0	0	0	1	Data Entry mode setting	Define data entry sequence A[2:0] = 011 [POR] A [1:0] = ID[1:0] Address automatic increment / decrement setting The setting of incrementing or decrementing of the address counter can be made independently in each upper and
0	1		0	0	0	0	0	A <sub>2</sub>	Aı	A <sub>0</sub>		lower bit of the address.  00 - Y decrement, X decrement,  01 - Y decrement, X increment,  10 - Y increment, X decrement,  11 - Y increment, X increment [POR]  A[2] = AM  Set the direction in which the address counter is updated automatically after data are written to the RAM.  AM= 0, the address counter is updated in the X direction. [POR]  AM = 1, the address counter is updated in the Y direction



0 0 0C 0 0 0 0 1 1 0 0 Booster Booster Enable with Phase 1, Phase 2 Soft start current and duration sett	
	and Phase 3
	ing.
Control   A[7:0] -> Soft start setting for Phase 1	
B[7:0] -> Soft start setting for Phase2	
= 9Ch [POR]	
C[7:0] -> Soft start setting for Phase3	
= 96h [POR]	
D[7:0] -> Duration setting	
= 0Fh [POR]	
Bit Description of each byte:	
Driving Strength	
Min Off Time Setting of GDR	
Time unit ]	
NA	
0100 2.6	
0101 3.2	
0110 2.0	
0 1 1 A6 A5 A4 A3 A2 A1 A0 0110 3.9 0111 4.6	
0 1 1 B6 B5 B4 B3 B2 B1 B0 1000 5.4	
1001 63	
0 1 1 C6 C5 C4 C3 C2 C1 C0 1001 0.3 1010 7.3	
0 1 0 0 D5 D4 D3 D2 D1 D0 1010 7.3	
0 1 0 0 03 04 03 02 01 00 1011 8.4 1100 9.8	
1100 9.8	
1110 13.8	
1110 13.8	
D[5:0]: duration setting of phase	
D[5:4]: duration setting of phase 3	
D[3:2]: duration setting of phase 2	
D[1:0]: duration setting of phase 1	
Bit[1:0] Duration of Phase	
Bit[1:0] Duration of Phase [Approximation]	
Bit[1:0] Duration of Phase [Approximation] 00 10ms	
Bit[1:0] Duration of Phase [Approximation] 00 10ms 01 20ms	
Bit[1:0] Duration of Phase [Approximation] 00 10ms	

0	0	12	0	0	0	1	0	0	0	0	SWRES ET	It resets the commands and parameters to their S/W Reset default values except R10h-Deep Sleep Mode During operation, BUSY pad will output high. Note: RAM are unaffected by this command. Temperature Sensor Selection
0	1		A7	A6	A5	A4	A3	A2	A1	A0	ure Sensor Control	A[7:0] = 48h [POR], external temperature sensor A[7:0] = 80h Internal temperature sensor
0	0	1A	0	0	0	1	1	0	1	0	_	Write to temperature register.
0	1		A7	A6	A5	A4	A3	A2	A1	A0	ure Sensor	A[11:0] = 7FFh [POR]
0	1		В7	В6	В5	В4	0	0	0	0	Control (Write to temperat ure register)l	
0	0	20	0	0	1	0	0	0	0	0	Master Activatio n	Activate Display Update Sequence The Display Update Sequence Option is located at R22h User should not interrupt this operation to avoid corruption of panel images.
0	0	21	0	0	1	0	0	0	0	1	Display	RAM content option for Display Update
0	1		A7	A6	A5	A4	A3	A2	A1	A0	Update	A[7:0] = 00h [POR]
0	1		B7	0	0	0	0	0	0	0	Control 1	B[7:0] = 00h [POR] A[7:4] Red RAM option 0000 Normal 0100 Bypass RAM content as 0 1000 Inverse RAM content A[3:0] BW RAM option 0000 Normal 0100 Bypass RAM content as 0 1000 Inverse RAM content B[7] Source Output Mode 0 Available Source from S0 to S175 1 Available Source from S8 to S167



0	0	22	0	0	1	0	0	0	1	0	Display	Display Update Sequence Option:
											Update	Enable the stage for Master Activation
												A[7:0]= FFh (POR)
												Operating sequence
												Parameter
												(in Hex)
												Enable clock signal 80
												Disable clock signal 01
												Enable clock signal
												Enable Analog
												C0
												Disable Analog
												Disable clock signal
												03
												Enable clock signal
0	1		۸ 7	A6	A5	A4	A3	A2	A1	A0	†	Load LUT with DISPLAY Mode 1
0	1		A7	ΑÖ	AS	A4	A3	A2	AI	AU		Disable clock signal
												91
												Enable clock signal
												Load LUT with DISPLAY Mode 2
												Disable clock signal
												99
												Enable clock signal
												Load temperature value
												Load LUT with DISPLAY Mode 1
												Disable clock signal
												B1
												Enable clock signal
												Load temperature value
												Load LUT with DISPLAY Mode 2
												Disable clock signal
												B9
												Enable clock signal
												Enable Analog
												Display with DISPLAY Mode 1
												Disable Analog
												Disable OSC
												C7
												Enable clock signal
												Enable Analog
				[ ``								Display with DISPLAY Mode 2
				1								Disable Analog
												Disable OSC
1												
												CF
												Enable clock signal
			7									Enable Analog
												Load temperature value
												DISPLAY with DISPLAY Mode 1
												Disable Analog
												Disable OSC
												F7
												Enable clock signal
												Enable Analog
												Load temperature value



0	0	24	0	0	1	0	0	1	0	0	Write RAM (Black White) / RAM 0x24	After this command, data entries will be written into the BW RAM until another command is written. Address pointers will advance accordingly For Write pixel:  Content of Write RAM(BW) = 1  For Black pixel:  Content of Write RAM(BW) = 0
0	0	26	0	0	1	0	0	1	1	0	Write RAM (RED) / RAM 0x26)	After this command, data entries will be written into the RED RAM until another command is written. Address pointers will advance accordingly.  For Red pixel:  Content of Write RAM(RED) = 1  For non-Red pixel [Black or White]:  Content of Write RAM(RED) = 0
0	0	2C	0	0	1	0	1	1	0	0	Write	Write VCOM register from MCU interface
0	1		A7	A6	A5	A4	A3	A2	A1	A0	VCOM register	A[7:0] = 00h [POR]
0	0	2D	0	0	1	0	1	1	0	1	OTP	Read Register for Display Option:
1	1		A7	A6	A5	A4	A3	A2	A1	A0	Register	A[7:0]: VCOM OTP Selection
1	1		В7	В6	B5	B4	В3	B2	B1	В0	Read for Display	(Command 0x37, Byte A) B[7:0]: VCOM Register
1	1		C7	C6	C5	C4	C3	C2	C1	C0	Option	(Command 0x2C)
1	1		D7	D6	D5	D4	D3	D2	D1	D0		C[7:0]~G[7:0]: Display Mode
1	1		E7	E6	E5	E4	E3	E2	E1	E0		(Command 0x37, Byte B to Byte F) [5 bytes]
1	1		F7	F6	F5	F4	F3	F2	F1	F0		H[7:0]~K[7:0]: Waveform Version
1	1		G7	G6	G5	G4	G3	G2	G1	G0		(Command 0x37, Byte G to Byte J)
1	1		Н7	Н6	H5	H4	Н3	H2	H1	Н0		[4 bytes]
1	1		I7	I6	I5	I4	I3	I2	I1	10	1	
1	1		J7	J6	J5	J4	J3	J2	J1	J0	1	
1	1		K7	K6	K5	K4	K3	K2	K1	K0	-	



0	0	2F	0	0	1	0	1	1	1	1	Status Bit Read	Read IC status Bit [POR 0x01] A[5]: HV Ready Detection flag [POR=0] 0: Ready 1: Not Ready A[4]: VCI Detection flag [POR=0] 0: Normal 1: VCI lower than the Detect level A[3]: [POR=0] A[2]: Busy flag [POR=0] 0: Normal 1: BUSY A[1:0]: Chip ID [POR=01] Remark: A[5] and A[4] status are not valid after RESET, they need to be initiated by command 0x14 and command 0x15 respectively
0	0	30	0	0	1	1	0	0	0	0	Program WS OTP	Program OTP of Waveform Setting The contents should be written into RAM before sending this command. The command required CLKEN=1. Refer to Register 0x22 for detail. BUSY pad will output high during operation
0	0	32	0	0	1	1	0	0	1	0	Write	Write LUT register from MCU interface
0	1		A7	A6	A5	A4	A3	A2	A1	A0	LUT	[153 bytes], which contains the content of
0	1		В7	В6	В5	В4	В3	B2	B1	B0	register	VS[nX-LUTm], TP[nX], RP[n], SR[nXY], FR[n] and XON[nXY]
0	1		:	:	:	:		:	:	:		Refer to Session 6.7 WAVEFORM
0	1		:	:	:	:	:		:	:		SETTING
0	1		:	:	:		:	:	<b>\</b> :	:		
0	1		:	:	:	:		:	:	:		
0	0	39	0	0	1	1	1	0	0	1	OTP program mode	OTP program mode A[1:0] = 00: Normal Mode [POR] A[1:0] = 11: Internal generated OTP programming voltage Remark: User is required to EXACTLY follow the reference code sequences
0	0	3C	0	0	1	1	1	1	0	0		Select border waveform for VBD A[7:0] = C0h [POR], set VBD as HIZ.



	_	I					-	6				
0	1		$A_7$	$A_6$	$A_5$	$A_4$	0	0	$A_1$	$A_0$		A [7:6] :Select VBD option
												A[7:6] Select VBD as 00 GS Transition,
												Defined in A[2] and
												A[1:0]
												01 Fix Level,
												Defined in A[5:4]
												10 VCOM
												11[POR] HiZ
												A [5:4] Fix Level Setting for VBD
												A[5:4] VBD level
												00 VSS
												01 VSH1
												10 VSL
												11 VSH2
												A[2] GS Transition control
												A[2] GS Transition control 0 Follow LUT
												(Output VCOM @ RED)
												1 Follow LUT
												A [1:0] GS Transition setting for VBD
												A[1:0] VBD Transition
												00 LUTO
												01 LUT1
												10 LUT2
												11 LUT3
0	0	44	0	1	0	0	0	1	0	0		Specify the start/end positions of the window
0	1		0	0	0	$A_4$	$A_3$	$A_2$	$A_1$	$A_0$	X - address	address in the X direction by an address unit A[4:0]: XSA[4:0], X Start, POR = 00h
0	1		0	0	0	$B_4$	$B_3$	$B_2$	$B_1$	$B_0$	Start /	B[4:0]: XEA[4:0], X End, POR = 0Ch
											End	B[1.0]. ALM [1.0], A End, I OR OCH
											position	
0	0	45	0	1	0	0	0	1	0	1		Specify the start/end positions of the window
0	1		<b>A</b> <sub>7</sub>	$A_6$	$A_5$	A <sub>4</sub>	A <sub>3</sub>	A <sub>2</sub>	$A_1$	$A_0$		address in the Y direction by an address unit
0	1		0	0	0	0	0	0	0	A <sub>8</sub>		A[8:0]: YSA[8:0], Y Start, POR = 00D3h B[8:0]: YEA[8:0], Y End, POR = 0000h
0	1		B <sub>7</sub>	B <sub>6</sub>	<b>B</b> <sub>5</sub>	B <sub>4</sub>	$\mathbf{B}_3$	B <sub>2</sub>	B <sub>1</sub>	$B_0$	End	Elevel, 1214[0.0], 1214, 1014
0	1		0	0	0	0	0	0	0	$B_8$	position	
0	0	4E	0	1	0	0	1	1	1	0		Make initial settings for the RAM X address in
0	1		0	0	0	A <sub>4</sub>	A <sub>3</sub>	$A_2$	$\mathbf{A}_1$	$A_0$	X	the address counter (AC)
											address counter	A[4:0]: XAD[4:0], POR is 00h
0	0	4F	0	1	0	0	1	1	1	1	-	Make initial settings for the RAM Y address in
0	1	41,	$A_7$	A <sub>6</sub>	$A_5$	$A_4$	$A_3$	A <sub>2</sub>	$A_1$	A <sub>0</sub>		the address counter (AC)
-				0	$\frac{A_5}{0}$			$\frac{A_2}{0}$	-	_	address	A[8:0]: YAD[8:0], POR is 00D3h
0	1		0	U	"	0	0	U	0	$A_8$	counter	



### 8. Optical Specification

Measurements are made with that the illumination is under an angle of 45 degree, the detection is perpendicular unless otherwise specified

Symbol	Parameter	Conditions	Min	Тур.	Max	Units	Notes
R	White Reflectivity	White	30	34	-	%	8-1
CR	Contrast Ratio	Indoor	15:1	20	-		8-1
							8-2
GN	2Grey Level	-	-	-	-		
KS	Black State L* value		-	15	19		8-1
WS	White State L* value		64	67	-		8-1
T update	Image update time	at 25 °C	-	3	-	sec	
Life		Temp:23±3°C Humidity:55±10%RH		5years			8-3

#### **Notes:**

- 8-1. Luminance meter: Eye-One Pro Spectrophotometer.
- 8-2. CR=Surface Reflectance with all white pixel/Surface Reflectance with all black pixels.
- 8-3. When the product is stored. The display screen should be kept white and face up

### 9. Handling, Safety, and Environment Requirements

#### Warning

The display glass may break when it is dropped or bumped on a hard surface. Handle with care. Should the display break, do not touch the electrophoretic material. In case of contact with electrophoretic material, wash with water and soap.

#### Caution

The display module should not be exposed to harmful gases, such as acid and alkali gases, which corrode electronic components. Disassembling the display module. Disassembling the display module can cause permanent damage and invalidates the warranty agreements.

Observe general precautions that are common to handling delicate electronic components. The glass can break and front surfaces can easily be damaged. Moreover the display is sensitive to static electricity and other rough environmental conditions.

#### **Data sheet status**

Product specification: This data sheet contains final product specifications.

#### Limiting values

Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

#### **Application information**

Where application information is given, it is advisory and does not form part of the specification.



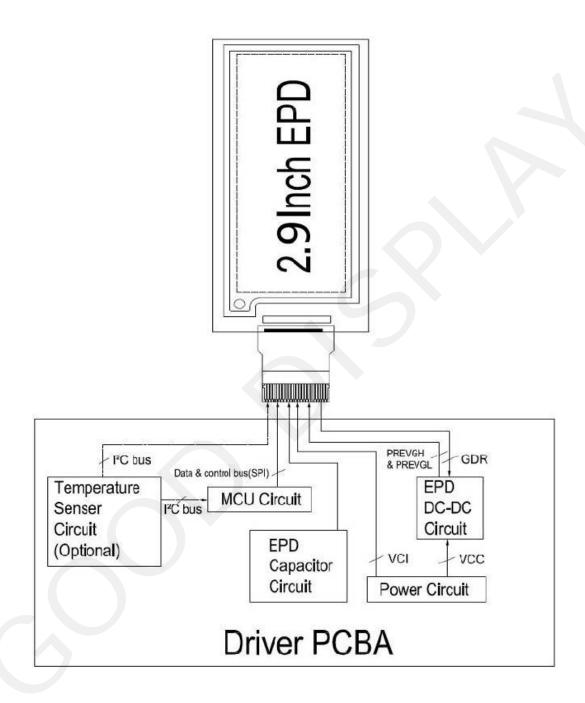
# 10. Reliability Test

NO	Test items	Test condition
1	Low-Temperature Storage	T = -25°C, 240 h Test in white pattern
2	High-Temperature Storage	T = +70°C, RH=40%, 240h Test in white pattern
3	High-Temperature Operation	T = +50°C, RH = 30%,240h
4	Low-Temperature Operation	0°C, 240h
5	High-Temperature, High-Humidity Operation	T=+40°C, RH=90%,240h
6	High Temperature, High Humidity Storage	T=+60°C, RH=80%,240h Test in white pattern
7	Temperature Cycle	1 cycle:[-25°C 30min]→[+70 °C 30 min] : 100 cycles Test in white pattern
8	UV exposure Resistance	765W/m² for 168hrs,40 °C Test in white pattern
9	ESD Gun	Air+/-15KV;Contact+/-8KV  (Test finished product shell,not display only)  Air+/-8KV;Contact+/-6KV  (Naked EPD display,no including IC and FPC area)  Air+/-4KV;Contact+/-2KV  (Naked EPD display,including IC and FPC area)

Note: Put in normal temperature for 1hour after test finished, display performance is ok.

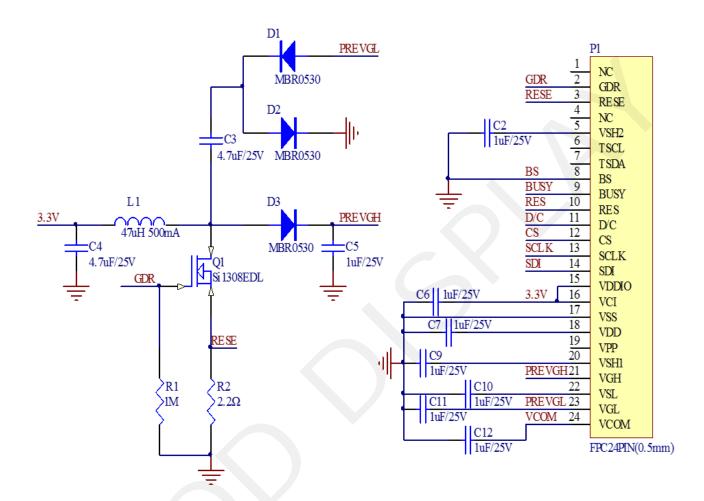


# 11. Block Diagram





# 12. Typical Application Circuit with SPI Interface





# 13. Matched Development Kit

Our Development Kit designed for SPI E-paper Display aims to help users to learn how to use E-paper Display more easily. It can refresh black-white E-paper Display and three-color (black, white and red/Yellow) Good Display 's E-paper Display. And it is also added the functions of USB serial port, Raspberry Pi and LED indicator light ect.

DESPI Development Kit consists of the development board and the pinboard.

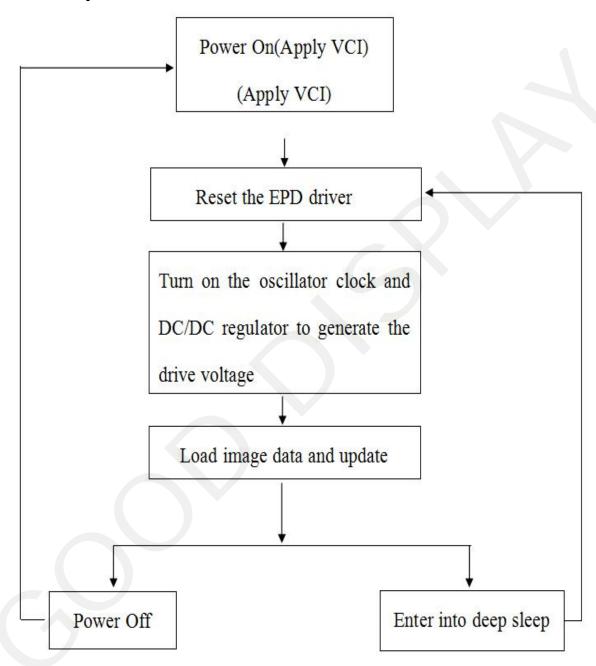
More details about the Development Kit, please click to the following link:

https://www.good-display.com/product/53/



# 14 Typical Operating Sequence

# 14.1 OTP Operation Flow





# **14.2 OTP Operation Reference Program Code**

ACTION	VALUE/DATA	COMMENT			
POWER ON					
delay	10ms				
	PIN CONFIG				
RESE#	low	Hardware reset			
delay	200us				
RESE#	high				
delay	200us				
Read busy pin		Wait for busy low			
Command 0x12		Software reset			
Read busy pin		Wait for busy low			
	SET VOLTAGE AND L	OAD LUT			
	1015 011 05 135 1	TOP LITTE			
	LOAD IMAGE AND U				
Command 0x24	4736bytes	Load BW image (128/8*296)(BW)			
Command 0x20					
Read busy pin		Wait for busy low			
Command 0x10	Data 0X01	Enter deep sleep mode			
	POWER OFF				



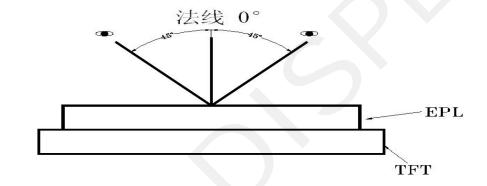
### 15.1 Environment

Temperature: 23±3℃, Humidity: 55±10%RH

# 15.2 Illuminance

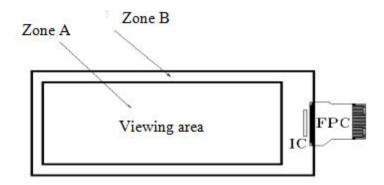
Brightness:1200~1500LUX;distance:20-30CM;Angle:Relate 45°surround.

# 15.3 Inspect method





# 15.4 Display area



# 15.5 Inspection standard

# 15.5.1 Electric inspection standard

NO.	Item	Standard	Defect level	Method	Scope
1	Display	Display complete Display uniform	MA		
2	Black/White spots	D≤0.25mm, Allowed 0.25mm < D≤0.4mm on N≤4, and Distance≥5mm 0.4mm < D Not Allow		Visual inspection	
3	Black/White spots (No switch)	L≤0.4mm, W≤0.1mm negligible 0.4mm <l≤1.0mm 0.1mm<w≤0.4mm="" allowable="" l="" n≤4="">1.0mm,W&gt;0.4mm, Not Allow</l≤1.0mm>	MI	Visual/ Inspection card	Zone A
4	Ghost image	Allowed in switching process	MI	Visual inspection	



5	Flash spots/ Larger FPL size	Flash spots in switching, Allowed FPL size larger than viewing area, Allowed	MI	Visual/ Inspection card	Zone A Zone B
6	Display wrong/Missing	All appointed displays are showed correct	MA Visual inspection		Zone A
7	Short circuit/ Circuit break/ Display abnormal	Not Allow			

# 15.5.2 Appearance inspection standard

NO.	Item	Standard	Defect level	Method	Scope
1	B/W spots /Bubble/ Foreign bodies/ Dents	D= $(L+W)/2$ D $\leq 0.25$ mm negligible 0.25mm $<$ D $\leq 0.4$ mm, N $\leq 4$ Allowed D $>$ 0.4mm, Not Allow	MI	Visual inspection	Zone A
2	Glass crack	Not Allow	MA	Visual / Microscope	Zone A Zone B
3	Dirty	Allowed if can be removed	MI		Zone A Zone B



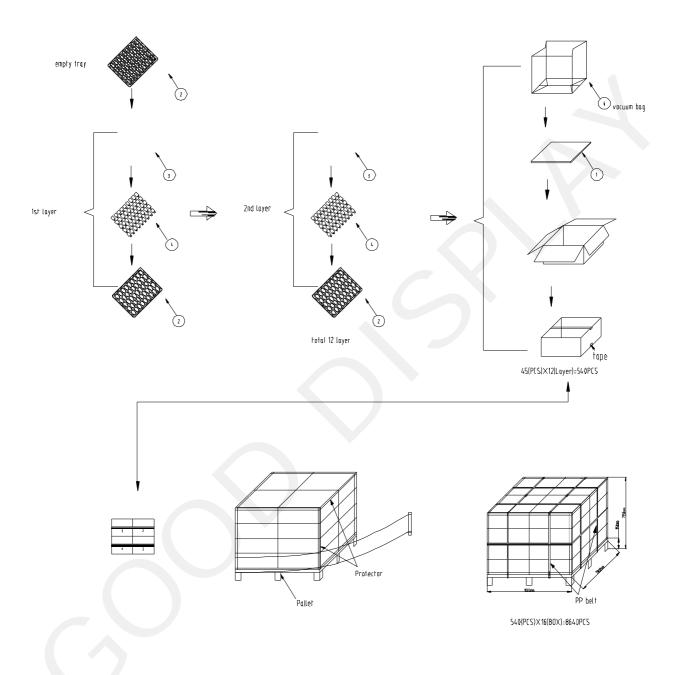
4	Chips/Scratch/ Edge crown	$X \le 3$ mm, $Y \le 0.5$ mm And without affecting the electrode is permissible $2$ mm $\le X$ or $2$ mm $\le Y$ Not Allow $W \le 0.1$ mm, $L \le 5$ mm, No harm to the electrodes and $N \le 2$ allow	MI	Visual / Microscope	Zone A Zone B
5	TFT Cracks	Not Allow	MA	Visual / Microscope	Zone A Zone B
6	Dirty/ foreign body	Allowed if can be removed/ allow	MI	Visual / Microscope	Zone A / Zone B
7	FPC broken/ Goldfingers exidation/ scratch	Not Allow	MA	Visual / Microscope	Zone B
8	TFT edge bulge /TFT chromatic aberration	TFT edge bulge: $X \le 3$ mm, $Y \le 0.3$ mm Allowed TFT chromatic aberration :Allowed	MI	Visual / Microscope	Zone A Zone B
9	PCB damaged/ Poor welding/ Curl	PCB (Circuit area) damaged Not Allow PCB Poor welding Not Allow PCB Curl≤1% Allow			
10	Edge glue height/ Edge glue bubble	Edge Adhesives H≤PS surface (Including protect film) Edge adhesives seep in≤1/2 Margin width Length excluding Edge adhesives bubble: bubble Width ≤1/2 Margin width; Length ≤5.0mm, n≤5	MI	Visual / Ruler	Zone B



11	Protect film	Surface scratch but not effect protect function, Allowed		Visual Inspection	
12	Silicon glue	Thickness ≤ PS surface(With protect film): Full cover the IC; Shape: The width on the FPC ≤ 0.5mm (Front) The width on the FPC≤1.0mm (Back) smooth surface,No obvious raised.	MI	Visual Inspection	
13	Warp degree (TFT substrate)	FPL  TFT  t≤1.0mm	MI	Ruler	
14	Color difference in COM area (Silver point area)	Allowed		Visual Inspection	



# 16. Packing





### 17. Precautions

- (1) Do not apply pressure to the EPD panel in order to prevent damaging it.
- (2) Do not connect or disconnect the interface connector while the EPD panel is in operation.
- (3) Do not touch IC bonding area. It may scratch TFT lead or damage IC function.
- (4) Please be mindful of moisture to avoid its penetration into the EPD panel, which may cause damage during operation.
- (5) If the EPD Panel / Module is not refreshed every 24 hours, a phenomena known as "Ghosting" or "Image Sticking" may occur. It is recommended to refreshed the ESL /EPD Tag every 24 hours in use case. It is recommended that customer ships or stores the ESL / EPD Tag with a completely white image to avoid this issue
- (6) High temperature, high humidity, sunlight or fluorescent light may degrade the EPD panel's performance. Please do not expose the unprotected EPD panel to high temperature, high humidity, sunlight, or fluorescent for long periods of time.
- (7) For more precautions, please click on the link: https://www.good-display.com/news/80.html